Inventor:

Salman Akram et al.

Title:

Methods of Sensing Temperature of an Electronic Device Workpiece

Assignee:

Micron Technology, Inc.

EL979949672
INFORMATION DISCLOSURE STATEMENT

PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, your attention is directed to the United States patents and other references listed on the attached Form PTO-1449. No admission is made regarding whether all the submitted references are prior art.

The listed references were cited by, or submitted to, the Office in the parent, co-pending application of the above-identified application. The above-identified application is a continuation application of co-pending application Serial No. 10/042,707, filed May 16, 2002, which is a continuation of U.S. Patent Application Serial No. 09/389,924, filed September 3, 1999, which was a divisional application of U.S. Patent Application Serial No. 09/032,184, filed February 27, 1998. Such prior disclosure is sufficient for the above-identified application as far as copies of the references are concerned. 37 C.F.R. § 1.98(d) and MPEP § 609(2).

Citation of these references is respectfully requested.

Respectfully submitted,

Dated:

By:

James D. Shaurette

Reg. No. 39,833

Form PTO-1449

## U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. MI22-2469 SERIAL NO. Filed Herewith

LIST OF ART CITED BY APPLICANT

(Use several sheets if necessary)

APPLICANT Salman Akram et al.

FILING DATE Filed Herewith GROUP Unknown

•						Filed Herewith			Unknown			
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Sheet 2 of 3 Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY, DOCKET NO. SERIAL NO. PATENT AND TRADEMARK OFFICE MI22-2469 Filed Herewith LIST OF ART CITED BY APPLICANT APPLICANT (Use several sheets if necessary) Salman Akram et al. FILING DATE GROUP Filed Herewith Unknown U.S. PATENT DOCUMENTS \*Examiner Document Date Name Class Subclas Filing Date Initial Number If Appropriate AA 6,377,060 B1 4/23/2002 Burkhart et al. ΑB 4,912,600 3/27/1990 Jaeger et al. AC 5,436,494 7/25/1995 Moslehi ΑD 5,969,639 10/19/1999 Lauf et al. ΑE 4,335,463 10/26/1982 Burns AF 3,710,251 1/9/1973 Hagge et al. 6,020,750 2/1/2000 AG Berger et al. ΑН 6,004,471 12/21/1999 Chuang 5,550,526 8/27/1996 Mottahed

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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Form PTO-1449

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTY. DOCKET NO. MI22-2469 SERIAL NO. Filed Herewith

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